Part Number: TO9-116

High Power TO9 Package Multi-Mode Fabry-Perot CW Wavelength at 1575nm Lensed Options Available

Features

- High Output Power
- High Dynamic Range
- High Efficiency
- Standard TO9
- Cost Effective

Application

- Professional Medical
- Home Use Medical
- Laser Range Finder
- Target Illumination
- Military Systems
- TOF LiDAR for Automotive and Drones
- Telecom OTDR
- Optical Comm



SemiNex delivers the highest available power at infrared wavelengths between 12xx and 19xx nm. When necessary, we will further optimize the design of our InP & GaSb laser chips to meet our customers' specific optical and electrical performance needs. Diodes, bars and packages are tested to meet customer and market performance demands. Typical results and packaging options are shown. Contact SemiNex for additional details or to discuss your specific requirements.





Specification

TO9-116

Optical	Symbol	Тур.	Units
Center Wavelength	λ _c	1575	nm (±20)
Output Power (CW)*	Pout	1.6	watts (±10%)
Emitter Width	W	95	μm
Spectral Width FWHM	Δλ	10	nm
Slope Efficiency	η	0.3	W/A
Fast Axis Div.	Θ⊥	28	deg FWHM
Slow Axis Div.	Θ _{II}	9	deg FWHM
Electrical	Symbol		Units
Power Conversion Eff.	η	12	%
Power Conversion Eff. Threshold Current		12 0.5	
	η		%
Threshold Current	η Ітн	0.5	% A
Threshold Current Operating Current	η Ι _{ΤΗ} Ι _{ορ}	0.5	% A A
Threshold Current Operating Current Operating Voltage	η І _{ТН} І _{ор} V _{ор}	0.5 8 1.7	% A A V

*Specified values are rated at a constant heat sink temperature of 20°C. **High temperature operation will reduce performance and MTTF. Unless otherwise indicated all values are nominal.

*Available Lenses & Caps

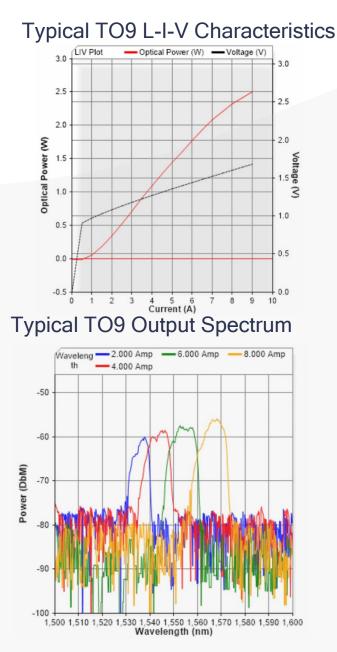
Part Number	Description	
TO9-116	TO9 Uncapped	
TO9-116-114	TO9 Cap, 4.6mm Tall	
TO9-116-115	TO9 5.8mm Tall Cap, Lens Collimated<5mrad f=590um,5mm lg	
TO9-116-140	TO9 5.8mm Tall Cap, Lens Matched f=171um, 5.0 lg	
TO9-116-161	TO9 Cap 5.8mm Tall	





SemiNex Laser Diodes TO9-116

Graphs & Data







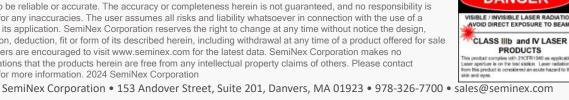
Mechanical Drawing TO9-116

Ø9.00_0.00 7.50±1.00 3XØ0.45-R3.05±0.05 PIN OUT: 1. LD CATHODE (-) 2. 3. CASE LD ANODE (+) 2 Ø2.54

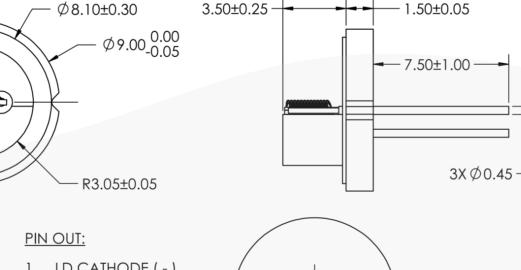
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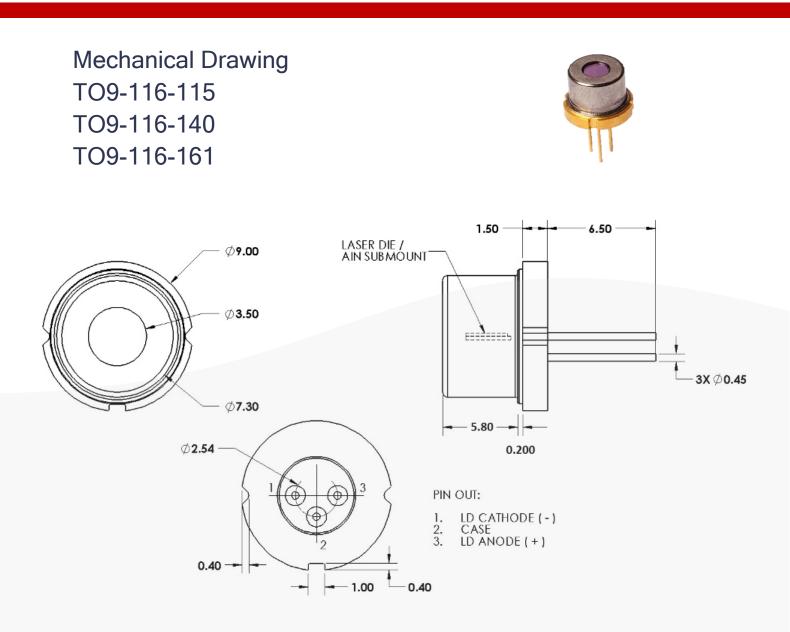
DANGER BLE / INVISIBLE LASER RAD OID DIRECT EXPOSURE TO CLASS IIIb and IV LASER PRODUCTS











High Power Laser Diode

TO-Cans

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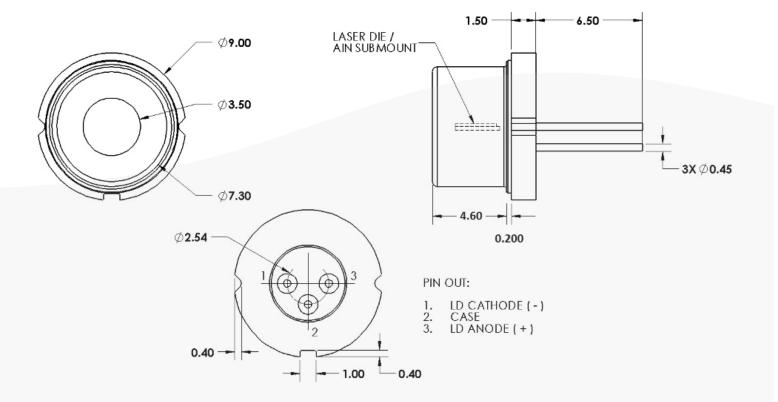


emi



Mechanical Drawing TO9-116-114





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